

P-CHANNEL ENHANCEMENT MODE MOSFET

## Product Summary (Typ @VGS = -4.5V, TA = +25°C)

BV <sub>DSS</sub>	Rds(on)	ID
001/	37mΩ @ V <sub>GS</sub> = -4.5V	-4.6A
-20V	49mΩ @ V <sub>GS</sub> = -2.5V	-3.7A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

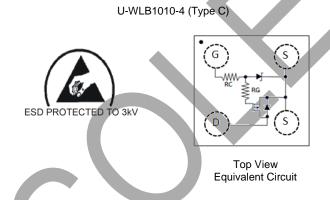
- Battery managements
- Load switches
- Battery protections

### **Features and Benefits**

- Low Qg & Qgd
- Small Footprint
- Low Profile 0.62mm Height
- ESD Protected Up To 3KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

## **Mechanical Data**

- Package: U-WLB1010-4
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal: Finish SnAgCu. Solderable per MIL-STD-202 Method 208 ①
- Terminal Connections: See Diagram Below



## Ordering Information (Note 4)

Part Number	Packago	Packing		
Part Number	Package	Qty.	Carrier	
DMP2042UCB4-7	U-WLB1010-4 (Type C)	3000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

,	2A	
	ΥM	

2A = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: J = 2022)

M or  $\overline{M}$  = Month (ex: 9 = September)

### Date Code Key

Notes:

Year	2016		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	D		J	K	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	VDSS	-20	V
Gate-Source Voltage	V <sub>GSS</sub>	-6	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	lD	-4.6	A
Continuous Drain Current (Note 5) V <sub>GS</sub> = -2.5V	ID	-3.7	A
Pulsed Drain Current (Note 6)	IDM	-16	A

# **Thermal Characteristics**

Symbol	Value	Unit
PD	0.75	W
R <sub>0JA</sub>	165	°C/W
PD	1.4	W
Reja	87	°C/W
TJ, TSTG	-55 to +150	°C
	PD Reja PD Reja	PD     0.75       RøJA     165       PD     1.4       RøJA     87

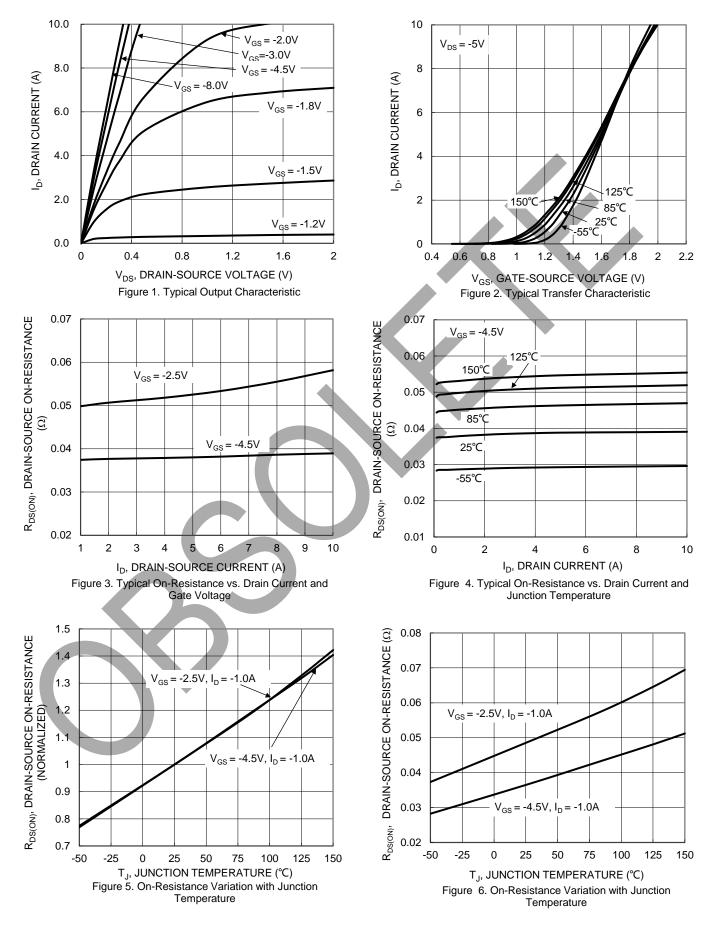
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Symbol	WIIII	тур	IVIAX	Unit	Test condition	
Drain-Source Breakdown Voltage	BVpss	-20	_	_	V	Vgs = 0V, Ip = -250µA	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	-	_	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	Igss			-100	nA	$V_{GS} = -6V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	-0.8	-1.2	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Otatia Dasia Osuma Os Dasistanas			37	45		Vgs = -4.5V, Ip =-1A	
Static Drain-Source On-Resistance	RDS(ON)	—	49	65	mΩ	Vgs = -2.5V, ID = -1A	
Forward Transfer Admittance	YFS	_	6.6	-	S	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1A	
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	Vgs = 0V, Is = -1A	
DYNAMIC CHARACTERISTICS (Note 9)						·	
Input Capacitance	Ciss	_	218				
Output Capacitance	Coss		148		pF	$V_{DS} = -10V$ , $V_{GS} = 0V$ , f = 1.0MHz	
Reverse Transfer Capacitance	Crss		11	_		1 - 1.00012	
Series Gate Resistance	Rg		20	_	Ω	f = 1MHz, V <sub>GS</sub> = 0V, V <sub>DS</sub> = 0V	
Series Clamp Resistance	Rc		5,000	_	12	I = IWHZ, VGS = 0V, VDS = 0V	
Total Gate Charge	Qg		2.5	_			
Gate-Source Charge	Qgs	—	0.4	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V,$	
Gate-Drain Charge	Q <sub>gd</sub>		0.4	_	nc	ID =-1A	
Gate Charge at VTH	Qg(TH)	—	0.2	_			
Turn-On Delay Time	tD(ON)	_	0.6	_			
Turn-On Rise Time	tR	—	0.8	_		V <sub>DS</sub> = -10V, V <sub>GS</sub> = -2.5V,	
Turn-Off Delay Time	tD(OFF)	_	1.4	—	μs	$R_G = 10\Omega$ , $I_D = -1A$	
Turn-Off Fall Time	tF	_	0.8				
Reverse Recovery Charge	Q <sub>RR</sub>	—	2.2	_	nC	$V_{DD} = -10V, I_F = -1.0A,$	
Reverse Recovery Time	t <sub>RR</sub>	—	10	—	ns	di/dt =100A/µs	

 Device mounted on FR-4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



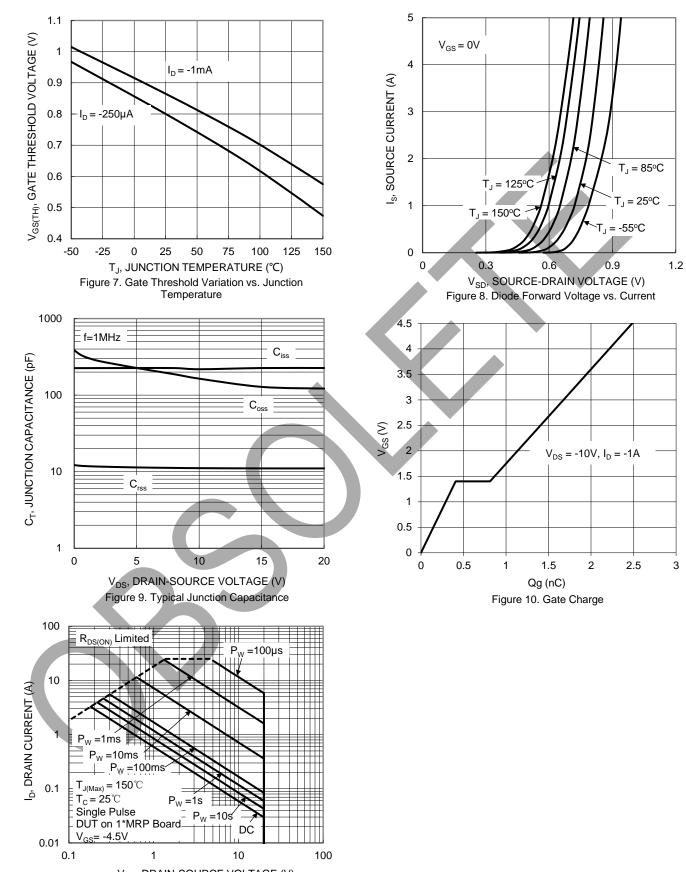
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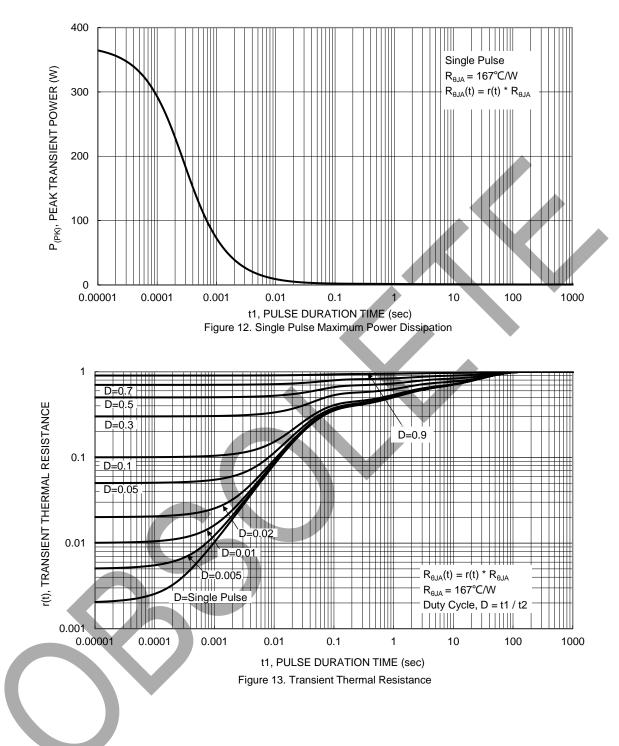
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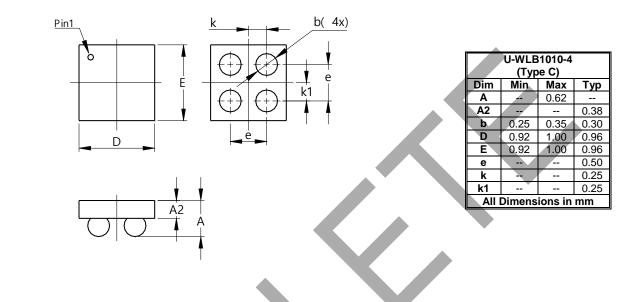




## **Package Outline Dimensions**

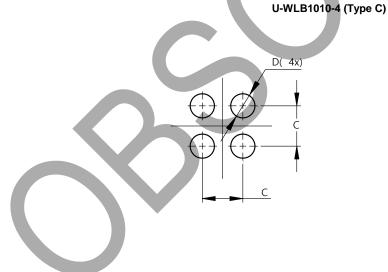
Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1010-4 (Type C)



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.500
D	0.300



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